INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC06 December 1990



Downloaded from Elcodis.com electronic components distributor

Semiconductors

Philips

74HC/HCT03

FEATURES

- · Level shift capability
- Output capability: standard (open drain)
- I_{CC} category: SSI

GENERAL DESCRIPTION

The 74HC/HCT03 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns

The 74HC/HCT03 provide the 2-input NAND function.

The 74HC/HCT03 have open-drain N-transistor outputs, which are not clamped by a diode connected to V_{CC} . In the OFF-state, i.e. when one input is LOW, the output may be pulled to any voltage between GND and V_{Omax} . This allows the device to be used as a LOW-to-HIGH or HIGH-to-LOW level shifter. For digital operation and OR-tied output applications, these devices must have a pull-up resistor to establish a logic HIGH level.

SYMBOL		CONDITIONS	TYP		
	PARAMETER	CONDITIONS	НС	нст	UNIT
t _{PZL} / t _{PLZ}	propagation delay	C_L = 15 pF; R_L = 1 k Ω ; V_{CC} = 5 V	8	10	ns
CI	input capacitance		3.5	3.5	pF
C _{PD}	power dissipation capacitance per gate	notes 1, 2 and 3	4.0	4.0	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o) + \sum (V_O^2/R_L) \times duty factor LOW, where:$

$$\begin{split} f_i &= \text{input frequency in MHz} \\ f_o &= \text{output frequency in MHz} \\ V_O &= \text{output voltage in V} \\ C_L &= \text{output load capacitance in pF} \\ V_{CC} &= \text{supply voltage in V} \\ R_L &= \text{pull-up resistor in } M\Omega \\ \Sigma & (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs} \\ \Sigma & (V_O^2/R_L) &= \text{sum of outputs} \end{split}$$

- 2. For HC the condition is $V_I = GND$ to V_{CC} For HCT the condition is $V_I = GND$ to $V_{CC} - 1.5$ V
- 3. The given value of C_{PD} is obtained with: $C_L = 0 \text{ pF}$ and $R_L = \infty$

ORDERING INFORMATION

See "74HC/HCT/HCU/HCMOS Logic Package Information".

December 1990

74HC/HCT03

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 4, 9, 12	1A to 4A	data inputs
2, 5, 10, 13	1B to 4B	data inputs
3, 6, 8, 11	1Y to 4Y	data outputs
7	GND	ground (0 V)
14	V _{CC}	positive supply voltage







FUNCTION TABLE

INP	UTS	OUTPUT				
nA	nB	nY				
L	L	Z				
L	н	Z				
Н	L	Z				
Н	Н	L				

Note

H = HIGH voltage level
L = LOW voltage level

Z = high impedance OFF-state

December 1990

74HC/HCT03

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134) Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
V _{CC}	DC supply voltage	-0.5	+7	V	
Vo	DC output voltage	-0.5	+7	V	
I _{IK}	DC input diode current		20	mA	for $V_I < -0.5$ V or $V_I > V_{CC}$ + 0.5 V
-I _{OK}	DC output diode current		20	mA	for $V_O < -0.5 V$
-l _O	DC output sink current		25	mA	for – 0.5 V < V_{O}
±I _{CC} ; ±I _{GND}	DC VCC or GND current		50	mA	
T _{stg}	storage temperature range	-65	+150	°C	
P _{tot}	power dissipation per package				for temperature range; –40 to +125 °C 74HC/HCT
	plastic DIL		750	mW	above +70 °C: derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 °C: derate linearly with 8 mW/K

74HC/HCT03

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications", except that the V_{OH} values are not valid for open drain. They are replaced by I_{OZ} as given below.

Output capability: standard (open drain), excepting V_{OH} I_{CC} category: SSI

Voltages are referenced to GND (ground = 0 V)

	PARAMETER			-	T _{amb} (°	C)		TEST CONDITIONS				
SYMBOL		74HC									v	OTHER
STIVIDOL		+25		-40 to +85 -		-40 to +125			V _{CC}	VI	OTHER	
		min.	typ.	max.	min.	max.	min.	max.				
I _{OZ}	HIGH level output leakage current			0.5		5.0		10.0	μA	2.0 to 6.0	V _{IL}	$V_O = V_{O(max)}^{(1)}$ or GND

Note

1. The maximum operating output voltage ($V_{O(max)}$) is 6.0 V.

AC CHARACTERISTICS FOR 74HC

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

				-		TEST CONDITIONS					
SYMBOL							WAVEFORMS				
STMBOL	PARAMETER	+2		+25		-40 to +85		-40 to +125		V _{CC}	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.			
t _{PZL} /	propagation delay		28	95		120		145		2.0	Fig.6
t _{PLZ}	nA, nB to nY		10	19		24		29	ns	4.5	
			8	16		20		25		6.0	
t _{THL}	output transition time		19	75		95		110	ns	2.0	
			7	15		19		22		4.5	Fig.6
			6	13		16		19		6.0	

74HC/HCT03

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see "74HC/HCT/HCU/HCMOS Logic Family Specifications", except that the V_{OH} values are not valid for open drain. They are replaced by I_{OZ} as given below.

Output capability: standard (open drain), excepting V_{OH} I_{CC} category: SSI

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T _{amb} (°C)								TEST CONDITIONS		
			74HCT									
		+25		-40 to +85 -		-40 to +125			V _{CC}	VI	OTHER	
		min.	typ.	max.	min.	max.	min.	max.				
I _{OZ}	HIGH level output leakage current			0.5		5.0		10.0	μA	4.5 to 5.5	V _{IL}	$V_O = V_{O(max)}^{(1)}$ or GND

Note

1. The maximum operating output voltage ($V_{O(max)}$) is 6.0 V.

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
nA, nB	1.0

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6 ns$; $C_L = 50 pF$

	PARAMETER				T _{amb} (°		TEST CONDITIONS				
SYMBOL					74HC			WAVEFORMO			
		+25			-40 to +85		–40 to +125			V _{CC}	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.			
t _{PZL} / t _{PLZ}	propagation delay nA, nB, to nY		12	24		30		36	ns	4.5	Fig.6
t _{THL}	output transition time		7	15		19		22	ns	4.5	Fig.6

74HC/HCT03

AC WAVEFORMS



TEST CIRCUIT AND WAVEFORMS





Definitions for Figs. 7, 8:

- C_L = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).
- R_T = termination resistance should be equal to the output impedance Z_O of the pulse generator.
- $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint on t_r , t_f with 50% duty factor.

		t _r ; t	^t f	
FAMILY	AMPLITUDE	V _M	f _{max} ; PULSE WIDTH	OTHER
74HC	V _{CC}	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

74HC/HCT03

APPLICATION INFORMATION





Notes to Figs 9 and 10

If $V_P - V_{CC}$ (R) > 0.5 V a positive current will flow into the receiver (as described in the "USER GUIDE"; input/output protection), this will not affect the receiver provided the current does not exceed 20 mA. At V_{CC} < 4.5 V, R_{ON} (max) is not guaranteed; R_{ON} (max) can be estimated using Figs 33 and 34 in the "USER GUIDE".

Note to Application information

All values given are typical unless otherwise specified.

PACKAGE OUTLINES

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".

December 1990

8